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Pr:KMgY3F12
La(Al 0.75 C0.25)03

Gd₂SiO₅ La₂SiO₅

underwater communication

Cd doped

LaA103

(La_{0.98}^{Ba}_{0.02})(Al_{0.98}^{Zr}_{0.02})0₃ (La_{0.98}^{Sr}_{0.02})(Al_{0.98}^{Zr}_{0.02})0₃

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Blue green lasers are required for communication under sea water. Currently, no solid-state laser shows inherent fluorescence in the blue green spectrum. Preliminary data at ONR had shown that Ce:LaAlO3 offers promise for communication under sea water. LaAlO3 exhibits a phase transformation at 435°C which creates problems in growing high quality crystals. Initial emphasis of the program was on making suitable additions to the LaAlO, in order to achieve a cubic perovskite structure which eliminates the phase transition. A composition of , (please turn page over

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Block 22 continued.

La(Al $_{0.75}$ Sc $_{0.25}$)0 $_{3}$ was identified as cubic; however, high quality crystals could not be grown because of difficult crystal growth parameters, which could not be obtained with available equipment. Two other compositions - $(\text{La}_{0.98}^{\text{Ba}}_{0.02})(\text{Al}_{0.98}^{\text{Zr}}_{0.02})^{0}_{3}$ and $(\text{LA}_{0.98}^{\text{Sr}}_{0.02})(\text{Al}_{0.98}^{\text{Zr}}_{0.02})^{0}_{3}$ - were also produced with cubic structure. Since Ba containing compound may exhibit quenching of fluorescence, the Sr compound may be useful for solid state laser applications. These bluish green crystals are not expected to show flu escence in the blue-green spectral region.

In order to develop other crystals with lower melting point, an effort was also placed on Ce:Gd2SiO5, Ce:La2SiO5 and Pr:KMgY3F12. These samples were delivered to ONR for evaluation of fluorescence.

Ce: Gd₃Sc₂Al₃O₁₂ (Ce: GSAG) crystals were also grown by HEM. These crystals offer promise for solid state laser applications; however, it is necessary to grow improved quality crystals for evaluation of laser performance.

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INVESTIGATION OF Ce³⁺ DOPANT

IN APPROPRIATE HOSTS

FOR BLUE GREEN LASERS

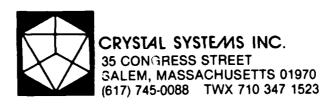
Final Report
ONR Contract No. N00014-82-C-0747
Covering period September 1, 1982 - July 31, 1985

Principal Investigator - C. P. Khattak Program Manager - F. Schmid



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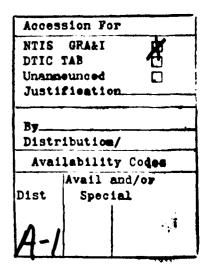


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INVESTIGATION OF Ce3+ DOPANT IN APPROPRIATE HOSTS FOR BLUE-GREEN LASERS

1.0 Introduction

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Underwater communication can be achieved with solid state laser sources in the blue-green spectral region. The wave length of most interest for these laser sources should be centered at ~ Therefore, crystals exhibiting blue-green luminescence considerable interest solid state as Ce3+:Y3Al5O12 (YAG) exhibits a broad luminescence centered around 520 nm^{1,2} based upon the Ce^{3+} d \rightarrow f luminescent transition³. This emission in Ce^{3+} :YAG is at too low energy and, therefore, precludes laser action 4 . The Ce $^{3+}$ in YAG occupies the center of the cube of oxygen ions. In lattices such as ScBO3 where Ce3+ is in octaheatal coordination with oxygen ions, the emission is typically observed at wavelengths less than 420 nm². symmetry-sensitive luminescence spectra are in keeping with the crystal field theory.

Based on the above considerations, luminescence was expected from Ce^{3+} centered at approximately 480 nm when the host lattice incorporated Ce^{3+} in a cubic symmetry with the oxygen in 8-fold coordination. In view of this, it was desirable to develop an appropriate host lattice for a blue-green laser using Ce^{3+} as the dopant.

The perovskite system appears to be an appropriate choice as an oxide host lattice. In this system LaAlO $_3$ appears to be an appropriate choice because of its large band gap, strong crystal field, and high thermal conductivity. However, the phase transition 5 at 435°C has presented considerable problems in trying to grow it in single crystal form. Therefore, additions to LaAlO $_3$ have to be made so as to suppress the phase transitions and, therefore, be able to grow single crystals. Some indication

of blue-green luminescence in Ce^{3+} doped $La(Al,Sc)O_3$ has been observed⁶; however, this sample was not well characterized.

During initial stages of the present program, efforts were made to study the feasibility of Ce3+:La(Al,Sc)O3 crystal growth by the Heat Exchanger Method (HEM™). After initial experiments, emphasis was placed on evaluating different materials which could be used as hosts for Ce^{3+} . A number of different hosts were formed which showed luminescence at wave lengths other than 480 nm or showed non-cubic symmetry so that large crystals could not be grown. Some of the compositions were identified which showed cubic symmetry. However, large single crystals could not be grown because of very stringent requirements for crystal growth, such as high temperatures of approximately 2200°C, high pressure to prevent volatilization and neutral/reducing atmosphere to retain Ce3+, etc. Even though solid state laser crystals which show luminescence in the blue-green spectral region were not grown, a number of materials were identified which could be grown in single crystal form for laser applications.

2.0 Heat Exchanger Method (HEM™)

The Heat Exchanger Method (HEM) is being used for commercial production of sapphire and silicon crystals 7,8 and has been adapted for the growth of a number of solid state laser crystals 9,10. The salient features of the process are shown in Figure 1. The crucible with the seed positioned at the bottom is loaded with charge and placed on top of the heat exchanger. After evacuation, heat is supplied by the graphite heater and the charge is melted. The seed is prevented from melting by forcing gaseous helium through the heat exchanger.

After sufficient meltback of the seed is achieved, growth is started by increasing the flow of helium and thereby decreasing the heat exchanger temperature. The liquid temperature gradients are controlled by the furnace temperature while the temperature gradient in the solid is controlled by the heat exchanger temperature. Crystal growth is achieved by controlling the heat input as well as the heat extraction. After solidification is complete, the gas flow through the heat exchanger is decreased to equilibrate the temperature throughout the crystal during the annealing and cooldown stage.

HEM is the only crystal growth process in which independent liquid and solid temperature gradients are achieved without movement of the crucible, heat zone or crystal. After the crystal is grown, it is still in the heat zone and can be cooled at a controlled rate to relieve solidification stresses. This unique capability allowed the growth of sapphire up to 32 cm diameter and weighing about 50 kg without cracking due to thermal stresses associated with such large sizes.

A distinguishing feature of the HEM, as compared with Czochralski (Cz) or top-seeded processes, is that the solid-liquid interface is submerged beneath the surface and is surrounded by the melt. Under these conditions the thermal and mechanical perturbations are damped out by the surrounding molten mass before they reach interface. This results in uniform

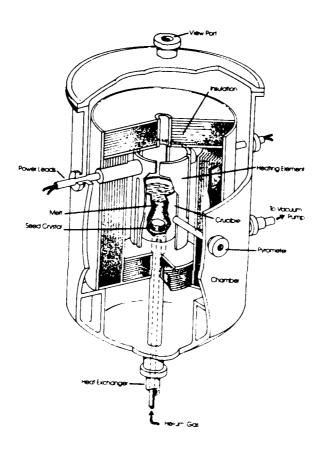


Figure 3. Schematic of HEM Furnace.

temperature gradients at the interface; consequently, neither the crystal nor the crucible is rotated. In the Cz process growth occurs at the melt surface where the local gradients vary sufficiently to cause solidification and remelting of the crystal. These features of HEM produce uniform growth and the only sapphire which is free of light scatter.

In the HEM growth, after the crystal is grown, the temperature of the furnace is reduced to just below the solidification temperature and the helium flow is reduced at a desired rate. The whole crystal can therefore be brought to high temperatures to anneal the solidification stresses and is then cooled uniformly at the controlled rate. Because in situ annealing is part of the solidification cycle, HEM can reduce the defect density. Further, the last and most impure material to solidify is along the crucible walls, where it can be removed.

In the case of sapphire and silicon, it was demonstrated that once crystal growth parameters are established, large crystals can be grown.

The hEM is currently being adapted for the growth of $Ti:Al_2O_3$, $Gd_3Sc_2Al_3O_{12}$ (GSAG), GaAs, CdTe, $Co:MgF_2$, aluminum oxynitride (ALON) and BaF_2 crystals.

From an economic point of view, HEM is a low-cost process. The furnace is automated and well insulated, which results in low labor and low energy costs.

3.0 Experimental Results

The objective of the program was to develop an appropriate host lattice for the Ce^{3+} dopant ion in order to produce bluegreen luminescence which could be utilized for communication through sea water. During the initial stages of the program, emphasis was placed on perovskite oxides.

Simple perovskites can be identified as ABO3 type compounds. LaAlO3 appeared to be an appropriate choice because of desirable properties. The phase transition at 435°C presented problems in growing this material in single crystal form. Suitable ions were substituted for Al in the B site in order to suppress the phase transition. In later stages, substitutions were also made for La in the A site. While these substitutions were made with trivalent ions, it was observed that the dopant Ce ion could easily go into tetravalent state because of nonstoichiometry of the oxygen sites. Substitutions were also made with divalent ions in the A site and tetravalent ions in the B Toward the end of the experimental phase, host lattices other than the perovskite, such as garnets, A2SiO5 type compounds and fluoride systems, were also evaluated. The details of the experiments carried out during the experimental stage are described in Table I. Samples were provided to the Office of Naval Research and the fluorescence data was obtained at the Naval Research Laboratory. The discussion for each system evaluated is written below.

3.1 Ce^{3+} ; La(A1,Sc)O₃ as Host Lattice

3.1.1 Choice of This System

Rare earths have found their widest application in optically-pumped solid-state lasers. Of the approximately 200 crystalline lasers reported, all are based upon rare earths except for a few iron group ions and one actinide ion.

 Ce^{3+} has been shown³ to exhibit 5d \rightarrow 4f luminescent transition and therefore has potential for a solid state blue-

Table I. Details of Experimental Data

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ATION COMMENTS				Yellow on top, black on bottom.	Opaque,	Opaque. Air fired at 1200C.	Charge boiled out of crucible.	Held at 2040 for 36 hrs and cooled-charge melted. Air fired at 1200C.	Dark, opaque. Charge from Run #8	Opaque. Material observed outside crucible.	Light yellow translucent on top. Opaque, black on bottom.	3 crucibles loaded into furnace. Solid state synthesis, no melting.	Yellow on top, black on bottom.	Mat'l from 12A. Single phase, rhombohedral. Yellow to black.
SOLIDIFIC TIME (Hr)			87	144	112	145	136		148	66	28		111	67
SUPER- HEAT	25		15	10	30	09	шах	вах	шах	max	35		20	30
MELT TEMP.	2095		2105	2105	2040	2055	2110	2040	2120	2115	2060		2060	2050
CHARGE WT. (gm)	37.79	44.40	39.40	142.70	136.45	70.25	65.30	75.85	56.50	62.45	61.15	36.25	29.05	35.65
CHARGE COMPOSITION	(LaO.8Sc0.2) A103	La(Alo.8Sc0.2)03	La(AlO.8Sc0.2)03	LaAlo3	La (Alo. 8Sc0.2)03	La(AlO.8Sc0.2)03	La(AlO.8Sc0.2)03	La(AlO.8Sc0.2)03	La(AlO.8Sc0.2)03	La (Al0.7Sc0.3)03	La(Al0.7Sc0.3)03	La(All-xScx)03	La(Al0.5Sc0.5)03	La(A10.8Sc0.2)03
RUN NO.	-	7	С	4	Ŋ	9	7	c o	6	10	11	12	13	14
	CHARGE CHARGE MELT SUPER- SOLIDIFICATION COMPOSITION WT. (gm) TEMP. HEAT TIME (Hr)	CHARGE CHARGE MELT SUPER- SOLIDIFICATION COMPOSITION WT. (gm) TEMP. HEAT TIME (Hr) (LaO.8SCO.2)Alo3 37.79 2095 25	CHARGE CHARGE MELT SUPER- SOLIDIFICATION WT. (gm) TEMP. HEAT TIME (Hr) (LaO.8Sc0.2)AlO3 37.79 2095 25 La(AlO.8Sc0.2)O3 44.40	CHARGE CHARGE MELT SOLIDIFICATION VMT. (gm) TEMP. HEAT TIME (Hr) (LaO.8Sc0.2)Alo3 37.79 2095 25 La(Alo.8Sc0.2)O3 44.40 44.40 87 La(Alo.8Sc0.2)O3 39.40 2105 15 87	CHARGE CHARGE MELT SULDIFICATION (LaO.8Sc0.2)AlO3 37.79 2095 25 La(AlO.8Sc0.2)O3 44.40 144.40 15 87 La(AlO.8Sc0.2)O3 142.70 2105 10 144	CHARGE CHARGE CHARGE CHARGE MELT SUPER-SOLIDIFICATION (LaO.8Sc0.2)AlO3 37.79 2095 25 La(AlO.8Sc0.2)O3 44.40 2105 15 87 La(AlO.8Sc0.2)O3 142.70 2105 10 144 La(AlO.8Sc0.2)O3 136.45 2040 30 112	CHARGE CHARGE MELT SUPER- SOLIDIFICATION (LaO.8SCO.2)A103 37.79 2095 25 La(AlO.8SCO.2)O3 44.40 2105 15 87 La(AlO.8SCO.2)O3 142.70 2105 10 144 La(AlO.8SCO.2)O3 136.45 2040 30 112 La(AlO.8SCO.2)O3 70.25 2055 60 145	CHARGE CHARGE MELT SUPER- SOLIDIFICATION (LaO.8ScO.2)A103 37.79 2095 25 TIME (Hr) La(AlO.8ScO.2)O3 44.40 2105 15 87 La(AlO.8ScO.2)O3 142.70 2105 10 144 La(AlO.8ScO.2)O3 136.45 2040 30 112 La(AlO.8ScO.2)O3 70.25 2055 60 145 La(AlO.8ScO.2)O3 65.30 2110 nax 136	CHARGE CHARGE MELT SULDIFICATION (LaO.8SCO.2)A103 37.79 2095 25 La(AlO.8SCO.2)O3 44.40 2105 15 87 La(AlO.8SCO.2)O3 142.70 2105 10 144 La(AlO.8SCO.2)O3 136.45 2040 30 144 La(AlO.8SCO.2)O3 70.25 2055 60 145 La(AlO.8SCO.2)O3 65.30 2110 max 136 La(AlO.8SCO.2)O3 75.85 2040 30 145 La(AlO.8SCO.2)O3 75.85 2040 30 145	CHARGE CHARGE MELT SULDIFICATION (LaO.8ScO.2)A103 37.79 2095 25 La(AlO.8ScO.2)O3 44.40 2105 15 La(AlO.8ScO.2)O3 142.70 2105 10 La(AlO.8ScO.2)O3 136.45 2040 30 144 La(AlO.8ScO.2)O3 70.25 2040 30 145 La(AlO.8ScO.2)O3 65.30 2110 max 136 La(AlO.8ScO.2)O3 75.85 2040 30 145 La(AlO.8ScO.2)O3 75.85 2040 30 145 La(AlO.8ScO.2)O3 75.85 2040 30 145 La(AlO.8ScO.2)O3 75.85 2040 30 145	CHARGE CHARGE MELT SUPERATOR SOLIDIFICATION (LaO.8SCO.2)A103 37.79 2095 25 La(AlO.8SCO.2)O3 44.40 2105 15 87 La(AlO.8SCO.2)O3 142.70 2105 16 144 Yellow on 144 La(AlO.8SCO.2)O3 136.45 2040 30 145 Opaque. Jack on 146 Included at 2000 on 145 Included at 2000 on 145 Included at 2000 on 146 Included at 2000 on 146	CHARGE VAT. (9m) TEMP. TEMP. NELT HEAT SOLIDIFICATION (LaO.8ScO.2)A103 37.79 2095 25 La(AlO.8ScO.2)O3 39.40 2105 15 87 La(AlO.8ScO.2)O3 142.70 2105 10 144 Yellow on 144 La(AlO.8ScO.2)O3 136.45 2040 30 112 Opaque. Jen 145 La(AlO.8ScO.2)O3 70.25 2055 60 145 Opaque. Jen 146 La(AlO.8ScO.2)O3 75.85 2040 30 116 Held at 3 coled-cl 146 La(AlO.8ScO.2)O3 56.50 2120 3 148 Dark, opa 146 La(AlO.8ScO.2)O3 56.50 2120 3 148 Dark, opa 151 La(AlO.7ScO.3)O3 62.45 2115 3 148 Dark, opa 150 La(AlO.7ScO.3)O3 61.15 3 2 3 2 3 2	CHARGE CHARGE MT. (gm) TEMP. SUPERATE TIME (Hr) (LaO.8SCO.2)A103 37.79 2095 25 La(AlO.8SCO.2)O3 44.40 2105 15 87 La(AlO.8SCO.2)O3 136.45 2105 10 144 Yellow on Lack and Control La(AlO.8SCO.2)O3 136.45 2040 30 112 Opaque. July La(AlO.8SCO.2)O3 70.25 2055 60 145 Opaque. July La(AlO.8SCO.2)O3 75.85 2040 30 136 Charge bot Control La(AlO.8SCO.2)O3 75.85 2040 30 145 Opaque. July La(AlO.8SCO.2)O3 75.85 2040 30 148 Dark, opace La(AlO.8SCO.2)O3 56.50 212 30 Control Control La(AlO.8SCO.2)O3 62.45 2115 30 Control Control La(AlO.7SCO.3)O3 61.15 35 28 Light yell La(All-xSCX)O3 36.25 35 Control C	CHARGE WIT. (gm) TEMP. HEAT TIME (Hr) (LaO.8SCO.2)A103 37.79 2095 25 La(AlO.8SCO.2)A103 44.40 1 87 La(AlO.8SCO.2)O3 142.70 2105 15 87 La(AlO.8SCO.2)O3 136.45 2040 30 112 0paque. La(AlO.8SCO.2)O3 136.45 2040 30 114 Yellow or La(AlO.8SCO.2)O3 65.30 210 87 136 Charge by La(AlO.8SCO.2)O3 75.85 2040 3 148 party april La(AlO.8SCO.2)O3 75.85 2040 3 148 bark, ope La(AlO.8SCO.2)O3 75.85 215 3 148 bark, ope La(AlO.8SCO.2)O3 65.50 215 3 2 1 La(AlO.8SCO.2)O3 65.50 215 3 2 8 148 bark, ope La(AlO.7SCO.3)O3 61.15 3 2 3 3 2 3

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Table I. Details of Experimental Data

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COMMENTS	Mat'l. synthesized in 12C opaque.	'Mat'l. from 12B two phase.	Semi-translucent. Yellow top single phase.	Translucent, lt. green bottom. opaque top.	Darker lower portion, light yellow top.	Several interfaces, some clear areas. Also black & yellow.	Translucent center, opaque bottom	Yellow, translucent top, opaque bottom.	Dark grey, crystalline. Operated under vacuum because of heating element problems.	Significant material loss.	Fragmented. Small grain size.
SOLIDIFICATION TIME (Hr)	99	114	136	112	142	119	182	119	141	88	74
SUPER- HEAT	30	40	50	30	4	4	40	пах	0	25	25
MELT TEMP.	2060	2040	2040	2065	2060	2070	2070	2075 1	2060	2075	2075
CHARGE WT. (gm)	19.95	26.25	35.40	53.40	38.15	90.70	94.30	95.30	91.80	06.66	92.25
CHARGE COMPOSITION	La(A10.5Sc0.5)03	La(Al0.7Sc0.3)03	La(Al0.75Sc0.25)03	La(A10.8Sc0.2)03	La(Al0.75Sc0.25)03	La(Al0.75Sc0.25)03	'a(Al0.75Sc0.25)03	La (A10.75Sc0.25)03	La (Alo.75sco.25)03	LaA103	LaA103
RUN NO.	15	16	17	18	19	20	21	22	23	24	25

Table I. Details of Experimental Data

STATES STATES

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	ION COMMENTS	Charge contained in isolated tungsten/moly chamber. inside furnace.	Same chamber as 26, same charge as 26. Charge melted, carbon contamination evident.	Melt not visible.	Solid state synthesis, not melted. New isolated tungsten chamber.	Solid state synthesis. Grey film on outside, white interior.	White mat'l. from #30 ground & pressed. Sintering experiment.	Mat'l. from #31. White crystalline.	Mat'l. from #32. Melted.	Blue, white, yellow. Sintered mass.	Blue, white, yellow mass Sintered.	Sintered. White.	
	SOLIDIFICATION TIME (Hr)		8	69				42	25				
70 511111111	SUPER- HEAT							20					
	MELT TEMP.		16.70 2080 max	29.35 2080 max				2080	40.94 2120 max				
	CHARGE WT. (gm)	16.70	16.70	29.35	34.80	55.79	50.79	48.78	40.94	47.68	40.80	22.17	
	CHARGE COMPOSITION	La(Alo.75Sco.25)03	La (Alo. 75Sco. 25) 03	La(Al0.75Sc0.25)03	La(Alo.75Sc0.25)03	La (Alo. 33Sco. 66) 03	La (Alo.33Sco.66)03	La (Alo.33Sco.66)03	La(A10.33Sc0.66)03	(La0.5Gd0.5)Sc03	(La0.5Gd0.5)Sc03	(La0.75Gd0.25)Sc03	(Ba0.5La0.5)Zr0.5Sc0.5)
	RUN NO.	56	27	28	29	30	31	32	33	34	35	36	37

Table I. Details of Experimental Data

ON COMMENTS	Sintering experiment.	Sintered. Majority phase-cubic.	Multiphases.	Held at 80% power for 4 hrs and cooled.	Most mat'l. blue with green- yellow on o.d. Cubic symmetry.	Heat exchanger leak. Non- transparent crystallites. Blue-green fluorescence.	Solid-state synthesis. White with brown speckles.	Crystals a few millimeters in size.	Clean cubic.	Solid-state synthesis. Outside black. core, brownish-yellow.	Solid state synthesis. Substitute Sr for Ba to eliminate quenching.	Solid state synthesis.	
SOLIDIFICATION TIME (Hr)					40			59					
SUPER- HEAT					Ŋ	70		15					33
MELT TEMP.				2145	2120	1880		1857					1912
CHARGE WT. (gm)	24.12	21.93	18.45	48.17	21.05	31.71	47.85	63.55		58.78	22.22	43.91	42.26
CHARGE COMPOSITION	Gd(Sc0.5Al0.5)03	(LaAlO3)0.95(BaZrO3)0.05	(LaAlO3)0.5(BaZrO3).05	BaZrO3	(LaAlO3).95(BaZrO3).05	Gd3Sc2Al3012	Ba2rO3	Gd3Sc2Al3012	(LaAlO3)0.98(BaZrO3).02	(LaAlO3)0.5(SrZrO3)0.5	(LaAlO3)0.95(SrZrO3)0.05	(LaAl03)0.95(SrZr03)0.05	Gd2SiO5
RUN NO.	38	39	40	41	42	43	4	4 5	46	47	48	49	20

Table I. Details of Experimental Data

SOLIDIFICATION COMMENTS TIME (Hr)	Solid state synthesis. La(OH)3 after standing in air.	2 Sample from Airtron.	Sample from Airtron. Lost power after melt. Sample cooled rapidly.	Remelt of #50/A. Several large crystallites.	4 Melted one phase. Ceramic appear	7 Removed 52 from furnace and remelted.
		100	55		63	09
MELT SUPER- TEMP. HEAT		830 10	930	1001 max	1382	1900
CHARGE I WT. (9m) T	38.61	47.39	52.29	50.71	41.99	41.71
CHARGE COMPOSITION	51 La 2Si05	KMgYF#7	KMgYF#7	51A KMGYF#7	Gd2SiO5	52 A Gd2SiO5
RUN NO.	51	49A	50 A	51 A	52	52 A

green laser. The host material should have a large energy gap to lower-lying 4f states in order to prevent parasitic excited state absorption processes in the host conduction band. It is important to maintain Ce in trivalent state; the Ce^{4+} gives absorption. An oxide host lattice is desirable because of high thermal conductivity and strong crystal field. LaAlO $_3$ appears to be an appropriate choice as both La and Al are in trivalent state.

The perovskite LaAlO3 has a rhombohedral structure 11 at room This material is in the $R\bar{3}m$ space group with lattice parameters $a = 5.357 \text{\AA}$ and $\alpha = 60^{\circ} 06'$. The deviation from cubic symmetry is exhibited by the rhombohedral angle, α ; for α the material show cubic symmetry 12 . would transforms⁵ to the cubic structure above 435°C. If large crystals of LaAlO $_3$ are grown, they are expected to exhibit cracking during the cooldown stage through this transformation. Suitable substitutions are, therefore, necessary in the Al sites to expand the lattice such that a cubic structure is formed. A review of the ionic radii of trivalent rate earth ions 13, 15 shows that with the exception of the value scandium, these ionic radii are quite large and, in fact, are among the largest values for any trivalent ions. Therefore, scandium ions could be substituted in the Al sites of LaAlO $_3$. In fact, LaScO $_3$ has been reported in literature 16 . The ionic sizes Sc^{3+} and $A1^{3+}$ are 0.83 and 0.57Å, respectively; substitution, therefore, would expand the LaAlO3 lattice and tend towards cubic symmetry.

Ternary phase diagrams for La $_2$ O $_3$ -Al $_2$ O $_3$ -Sc $_2$ O $_3$ are not known. However, binary phase diagrams exist. From the La $_2$ O $_3$ -Al $_2$ O $_3$ phase diagram 17 (Figure 2) it can be seen that LaAlO $_3$ melts congruently at 2100°C. The Sc $_2$ O $_3$ -Al $_2$ O $_3$ phase diagram 18 (Figure 3) shows that at about 20 mole % Sc $_2$ O $_3$, a single phase solid solution phase is formed and the formation of α -Al $_2$ O $_3$ is prevented. The range of this solid solution phase is ~ 18 to 35 mole % Sc $_2$ O $_3$ at 1600 °C.

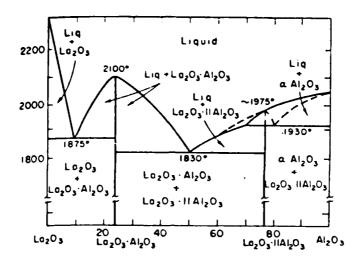


Figure 2. Phase Diagram for $A1_20_3$ - La_20_3 System

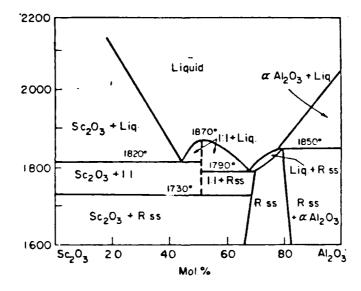


Figure 3. Phase Diagram for $A1_2^0_3$ -Sc $_2^0_3$ System

From theoretical considerations, therefore, it appears that $La(Al,Sc)O_3$ crystals can be grown with a cubic structure. This material can then be used as a laser host material for Ce dopant ions. Trivalent Ce will substitute for La sites and compounds $CeAlO_3$ and $CeScO_3$ are reported in literature 19,20 . The amount of Ce substitution necessary for lasing action is expected to be about 0.02%.

Initial work sponsored by the Office of Naval Research was an attempt at growing a crystal of $La(Al_0._8Sc_{0..2})0_3$ doped with 0.01% Ce. During one experiment a small amount of the charge was fused in an iridium crucible. The experiment was aborted because of melting of the crucible. Optical spectra taken of the fused sample was characteristic of a cubic phase. The sample was rather inhomogeneous; however, it demonstrated that a cubic phase is formed in the $La(Al,Sc)0_3$ system and spectra show encouraging results for laser properties 6 .

3.1.2 Crystal Growth of La(A1,Sc)O3 by HEM

Initial work was carried out to evaluate the appropriate crucible and the atmosphere to be used for a La(A1,Sc)O3 system. Since the ternary phase diagram is not known for this system, it is difficult to predict the various phases that can be formed in this system. It is essential to retain the dopant, Ce, in the trivalent state. Therefore, it is necessary to maintain a non-oxidizing atmosphere. Early work carried out under vacuum showed that the volatility of the phases formed resulted in a considerable loss of meltstock by evaporation. Further experiments were, therefore, under an argon atmosphere.

A molybdenum crucible was used which showed some reactivity with the charge at high temperatures. When molybdenum crucibles are used in vacuum, the volatile MoO_3 is removed; under argon atmosphere, this oxide is retained in the furnace chamber. Tungsten crucibles were found to be satisfactory.

Once the crucible and atmosphere were established, an attempt was made to grow LaAlO $_3$ crystals. The La $_2$ O $_3$ -Al $_2$ O $_3$ phase

diagram is shown in Figure 2. No problems were encountered and a few mm size crystals were obtained. An x-ray diffraction pattern of crystals from Experiment #4 was taken and the pattern showed rhombohedral symmetry and could be indexed on the basis of hexagonal cell size of a=5.34 Å c=13.10Å. The observed and calculated 'd' values are shown in Table II. This data compares well with the published values 11 , 21 for LaAlO3. An IRD-Guinier x-ray pattern was taken at Brookhaven National Laboratory and the pattern showed rhombohedral distortion of a cubic cell size of 3.8Å.

Experiments were carried out with a charge corresponding to $La(Al_{0..8}Sc_{0..2})0_3$. A molybdenum crucible was used and the lid on the crucible was held down with a weight placed on top of the cover. The material was taken up to $2120^{\circ}C$ and slowly cooled. X-ray analysis of this data showed a two-phase structure for a sample from Experiment #3. Both the phases were rhombohedral distortion of the perovskite structure with lattice parameters of 3.86 Å and 3.99 Å, respectively. This data shows that the perovskite cell size has been enlarged from 3.8 Å with the substitution of Sc ions for the Al ions.

Another experiment was carried out with $La(Al_{0..8}Sc_{0..2})o_3$ charge composition. This time no cover was placed on the tungsten crucible. The resultant material (#5W) showed a single-phase, rhombohedral symmetry with perovskite cell size of 3.83 Å. The Laue pattern showed the single crystal nature of the material.

Since the phase diagram of the ternary system $\text{La}_2\text{O}_3\text{-Al}_2\text{O}_3$ - Sc_2O_3 is not known, it is postulated that for the composition $\text{La}(\text{Al}_{0.8}\text{Sc}_{0.2})\text{O}_3$ two phases are formed. One of these phases is more volatile and during heating in the crucible without cover this phase volatilizes resulting in single-phase material. When a cover is placed on the crucible volatilization is minimized and two phases are formed. A review of the $\text{Al}_2\text{O}_3\text{-Sc}_2\text{O}_3$ binary phase diagram (Figure 2) shows that for 20 mole percent Sc_2O_3 substitution, a single phase is formed at high temperature;

TABLE II. Observed and calculated 'd' values of an x-ray diffraction pattern of LaAlO $_3$ based on hexagonal cell size of a=5.34 Å, c=13.10 Å

'd'	values	21.7
Observed	Calculated	hkl
3.79	3.78	012
2.67	2.67	110
2.28	2.28	021
2.18	2.18	006
1.89	1.89	024
1.73	1.73	211
1.69	1.69	122,116
1.54	1.54	300,214,018
1.339	1.336	208
1.339	1.335	220
1.260	1.260	306
1.190	1.195	128
1.190	1.194	134
1.140	1.140	0210,226,402
1.090	1.092	0012
	1	I .

however, a two-phase region exists at lower temperatures.

It was decided to pursue two approaches: first, to attempt solidification from a lower temperature with $La(Al_{0..8}Sc_{0..2})o_3$ composition to minimize volatilization; and second, to evaluate $La(Al_{0..7}Sc_{0..3})o_3$ composition.

An experiment was carried out in which La(Al_{0.8}Sc_{0.2})0₃ composition was heated to the 2020°C to 2040°C temperature range, held for about 36 hours and then cooled. No significant weight loss was observed and the boule (#8) after removal from the crucible is shown in Figure 4. Large crystallites are seen on the tcp surface. X-ray analysis of the ingot showed that it was not of rhombohedral symmetry, as was the case with other samples. The x-ray data could be indexed as a single-phase, orthorhombic structure with cell parameters a=5.08, b=5.65 and c=7.72 Å. A comparison of the observed and calculated d values is shown in Table III. The difference between the a and b lattice parameters appears large; the symmetry could be monoclinic. The perovskite unit cell is about 3.84 Å.

The material solidified under similar conditions in Experiment #10 using La(Al $_{0.7}\rm Sc_{0.3}$)03 showed a two-phase structure.

Work with the La(A1,Sc)O $_3$ system showed that, depending upon the composition as well as the experimental conditions, the symmetry was changed from rhombohedral to orthorhombic or monoclinic. During the stage when emphasis was placed on heating the material to well over 2100° C, significant weight loss was associated with each experiment. Once it was determined that with Sc substitutions the melting point of the compound was lower than the LaAlO $_3$, most of the experiments were carried out under low superheat conditions. Some of the compounds were analyzed after solid state synthesis to minimize volatilization from the melt. In Experiment #12, compounds of La(Al $_{1-x}$ Sc $_x$)O $_3$ with x=0.2, 0.3 and 0.5 were heated to about 1700°C and cooled. X-ray diffraction data showed two phases for all the three compounds; one phase was closer to LaAlO $_3$ lattice parameter (~ 3.8 Å) and

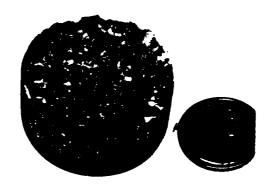


Figure 4. A view of an ingot of La(Al_{0.8}Sc_{0.2})0₃ after HEM solidification

TABLE III. Observed and calculated 'd' values of an x-ray diffraction pattern of $La(Al_{0.8}Sc_{0.2})^{0}$ 3 based on orthorhombic cell size of a=5.08, b=5.65, c=7.72 Å

' d '	values	1
Observed	Calculated	hk1
5.68	5.08	100
5.68	5.65	010
3.88	3.86	002
3.88	3.78	110
3.26	3.39	111
3.18	3.19	012
3.18	3.07	102
2.83	2.83	020
2.73	2.70	112
2.46	2.47	120
2.28	2.32	210
2.28	2.30	103
2.24	2.28	022
2.22	2.22	211
2.13	2.13	113
2.13	2.12	202
1.93	1.93	004
1.92	1.90	023
1.88	1.89	2 20
1.87	1.88	030

the second phase was of large cell (\sim 4 Å). On a qualitative basis the proportion of the second phase increased with increased substitution of Sc ions.

The composition corresponding to La(Al $_{0.8}$ Sc $_{0.2}$)0 $_3$ after sintering in Experiment #12 was used as meltstock in Experiment #14. With sintered meltstock the volatilization of charge is minimized. Single phase material of rhombohedral symmetry with a lattice parameter of 3.86Å was obtained. This data shows that Sc can be incorporated in LaAlO $_3$ and enlarge the lattice but will not change the symmetry to cubic. The crystals showed orange in the fluorescence spectra. This may be because Ce^{3+} is expected to show light green and Ce^{4+} yellow fluorescence. The high concentration of dopant used may have converted some of the Ce to the tetravalent state. The concentration of the dopant was reduced in the charge from 1% to 0.05%.

When material corresponding to La(Al $_{0..5}$ Sc $_{0..5}$)0 $_3$ was melted and directionally solidified by HEM in Experiment #15, two phases were observed in the structure, and the x-ray pattern was similar to the solid-state synthesized material of the same composition. This suggested that for Sc concentration between 20 and 50%, a transition in structure may be possible. Therefore, a sample corresponding to La(Al $_{0..75}$ Sc $_{0..25}$)0 $_3$ composition was melted and directionally solidified by HEM in Experiment #17. X-ray diffraction data on this sample showed a single phase cubic structure with a unit cell size of 3.83 Å. The data is shown in Table IV.

Thin sections cut out of the solidified material from Experiment #19 corresponding to $La(Al_{0.75}Sc_{0.25})0_3$ composition and lower dopant concentration showed translucency in the as-cut sections. Samples were sent to ONR for evaluation. It was seen that a blue fluorescence was observed in localized areas of a sample which was attributed to color centers in the sample. Another feature observed was that significant carbon contamination was observed in the samples. This contamination masked the structural as well as the optical properties. The

TABLE IV. X-ray diffraction data on sample corresponding to $La(Al_{0.75}Sc_{0.25})0_3$ composition (a=3.832 Å)

Intensity	d obs	dcalc	hkl
52	3.84	3.832	100
100	2.72	2.710	110
44	2.22	2.212	111
62	1.92	1.916	200
18	1.71	1.714	210
34	1.57	1.564	211
12	1.35	1.355	220
12	1.28	1.277	300,221
12	1.21	1.212	310
7	1.159	1.155	311
4	1.109	1.1062	222
4	1.063	1.0628	320
10	1.025	1.0241	321
4	0.955	0.9580	400
3	0.927	0.9294	410,322
5	0.900	0.9032	411,330
3	0.879	0.8791	331
5	0.855	0.8569	420
2	0.832	0.8362	421

source of carbon is from the graphite resistance furnace and is being transported via the vapor phase to the charge. Efforts were made to improve the quality of the $\text{La}(\text{Al}_{0.75}\text{Sc}_{0.25})0_3$ crystals in Experiments 20 through 23. These samples exhibited a range of fluorescence from orange to bluish white. The orange is associated with Ce^{4+} and blue to a combination of Ce^{4+} and color centers.

Two experiments (#26 and #27) were carried out to minimize the carbon transport. An extension tube was added to the crucible as shown in Figure 5. The charge after meltdown and solidification still showed carbon contamination. In the second experiment the extension tube was extended further to just below the viewport, but carbon contamination was still observed. At a temperature of ~ 2100°C, carbon contamination from a graphite heat zone is a serious problem. Refractory metal furnaces eliminate the carbon problems. However, they are designed to operate under vacuum, but for LaAlO₃ type compounds, it is necessary to operate under pressure to prevent volatilization of charge.

While simple perovskites usually show deviations from cubic symmetry, it is also possible to achieve cubic structure by ordering of ions. Based upon the tolerance factor and ionic sizes of A and B ions a composition corresponding to $\text{La}(\text{Al}_{0.33}\text{Sc}_{0.67})\text{O}_3$ was selected to evaluate whether cubic symmetry is achievable by ordering of Al and Sc ions. Experiments #30 through #33 were carried out using this composition. X-ray analysis showed that the major phase was orthorhombic with lattice parameters of a=5.61 Å, b=5.67 Å and c=8.02 Å with a minor phase which was cubic with a lattice parameter of 3.85 Å. These data are consistent with the cubic lattice parameter obtained with $\text{La}(\text{Al}_{0.75}\text{Sc}_{0.25})\text{O}_3$ composition.

The rhombohedral structure of LaAlO $_3$ can be enlarged with the addition of Sc in the lattice based on the data obtained for the La(Al $_{1-x}$ Sc $_x$)O $_3$ system. The enlargement of the structure reduces the deviations from ideal perovskite structure. At

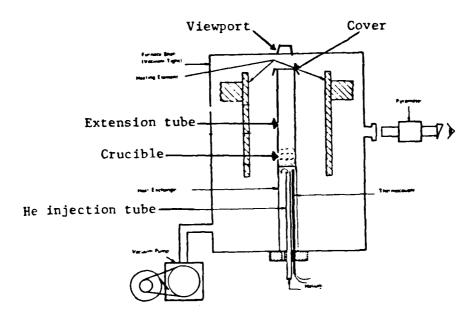


Figure 5. Experimental set-up to prevent carbon contamination

approximate value of x=0.25, single phase cubic structure can be obtained. For higher values of x, the structure changes to orthorhombic and continues to enlarge in cell size until all the Al is replaced by the Sc ions.

For an approximate composition of La(Al $_{0.75}$ Sc $_{0.25}$)0 $_3$ single phase cubic material can be produced; however, the composition range is narrow. These crystals should not exhibit twinning like the LaAlO $_3$ composition because of absence of phase transitions. Although single crystals were grown, the fluorescence spectra showed problems with color centers. The quality of the crystals could not be improved because of carbon contamination from the existing furnaces. Crystal growth at about 2100°C under argon atmosphere is very difficult with commercially available refractory metal furnaces.

3.2 Achievement of Cubic Symmetry in Other Perovskites.

After an initial emphasis on the $Ce:La(Al,Sc)O_3$ system described above, efforts were made to identify other perovskite oxides which could lead to a cubic symmetry. If cubic symmetry is achieved at room temperature, then phase transitions will be eliminated. With such materials, single crystal growth can be carried out and twinning and cracking problems will not be encountered. A number of mixed oxide perovskites were evaluated using this approach.

3.2.1 Correlation of Ionic Size and Tolerance Factor

LaAlO $_3$ exhibits a typical ABO $_3$ type perovskite structure. While none of the A 3 +B 3 +O $_3$ type compounds have the "ideal" cubic perovskite structure, the rhombohedral form of LaAlO $_3$ is only a slight distortion from the cubic structure. Partial substitutions of A and/or B ions in some perovskite compounds have led to the formation of cubic structures. For example, LaCoO $_3$ exhibits a rhombohedral structure 22,23 ; however, LaO $_5$ SrO $_5$ CoO $_3$ shows a cubic structure 24,25 . Similarly, BaCeO $_3$ is orthorhombic 26 , but BaCeO $_5$ UO $_5$ O $_3$ is cubic 27 . Substituted

perovskites usually show ordering of the A and/or B ions and lead to the formation of a larger unit cell size with a cubic structure.

Ordering of the ions takes place when there is a large difference in their charge or size. The range of ionic size that can form the perovskite structure is governed by the Goldschmidt tolerance factor, t. This factor for oxides is given by

t = $(R_A + R_O)/\sqrt{2}$ $(R_B + R_O)$ where R_A , R_B and R_O are the radii of the A, B and oxygen ions, respectively. The perovskite structure is stable within the range of 0.75 < t < 1.00 with t lying between 0.8 and 0.9 in most cases.

Using LaAlO $_3$ as a host lattice and partial substitution of Al with Sc, the tolerance factor for La(Al $_{1-x}$ Sc $_x$)O $_3$ changes from 0.9302 for x = 0 to 0.8167 for x = 1. The experimental work described above shows that for this system, when x = 0.25, a cubic structure may be formed. For this compound t = 0.8990.

Other suitable substitutions for La and Al are Gd and Ga, respectively. Literature values of the ionic radii of different ions are shown in Table V. Tolerance factor calculations for various systems with substitution for La or Al, as well as both La and Al, are shown in Table VI. It can be seen that the four systems indicated show a wide range of t values with all values being in the range of Goldschmidt criterion for formation of perovskite structure.

The cubic structure is formed because of ordering when there is a difference in valence or ionic size. In the systems discussed, ordering because of valence difference is not expected because all cations are trivalent. The difference in ionic sizes to achieve ordering for the $A^3+B^3+O_3$ system is not known; however, a study 12 of $Ba(M_{0.5}^{3+}Nb_{0.5}^{5+})O_3$ type compounds showed that the critical percentage difference in ionic radii between B ions which causes ordering lies between 7% and 17%. Calculations for La, Gd and Al, Ga systems show that the percentage difference in ioni radii is 17.5 and 12.7%, respectively.

TABLE V. Literature values of ionic radii for A^{3+} and B^{3+} ions

Atom	Ionic Radius, Å
La	1.14
Gd	0.97
Sc	0.81
Ga	0.62
A1	0.55
o ²⁻	1.32

TABLE VI. Tolerance factor, t, calculations of various perovskite structures using ionic radii in Table II.

tolerance factor, t		
x=0 y=0	x=0.5 y=0.5	x=1.0 y=1.0
0.9302	0.8697	0.8167
0.9302	0.9131	0.8966
0.9302	0.898	0.8659
0.9302	0.8816	0.8347
	x=0 y=0 0.9302 0.9302 0.9302	x=0 x=0.5 y=0 y=0.5 0.9302 0.8697 0.9302 0.9131 0.9302 0.898

Another advantage of these substituted compounds is that they are expected to have lower melting points. This will facilitate crystal growth and make it easier to retain Ce dopant in the trivalent state necessary for blue-green luminescence. This approach utilizes only trivalent ions and tends to facilitate keeping Ce in trivalent state.

Another approach is to utilize partial replacement of A ions with divalent ions and B ions with tetravalent ions. With this approach ordering may be achieved by differences in ionic sizes as well as charges on the ions. It may also be possible to obtain cubic symmetry without the ordering when multi-valent ions are used. For these purposes, mixtures of $A^{3+}B^{3+}O_{3}$ with $BaZrO_{3}$ and $SrZrO_{3}$ were evaluated because these ions do not exhibit multi-valence state and therefore are not expected to form Ce^{4+} state for the dopant.

3,2,2 Crystal Growth of Other Perovskite Compounds by HEM

In Experiments #34 through #36 achievement of cubic structure by ordering of A ions in the composition $(La_{1-x}Gd_x)Sco_3$ system with x=0.25 and 0.5 was investigated. The cubic phase was not obtained and the major phase was identified as orthorhombic with lattice parameter of a=5.766, b=7.980 and c=5.523 Å for #34.

Composition $Gd(Al_{0..5}Sc_{0..5})0_3$ in Experiment #38 also did not yield the cubic phase. Ga substitution in the B site was not attempted because of the formation of Ga_2O under reducing conditions and problems with maintaining stoichiometry.

In Experiments #37 and #40, a 50:50 mixture of BaZrO₃ with LaScO₃ and LaAlO₃, respectively, were attempted. In both cases, cubic enlarged cell expected from ordering was not observed. Similar results were achieved in Experiment #47 with (LaAlO₃)_{0.5}(SrZrO₃)_{0.5} composition.

Small additions of $BaZrO_3$ to $LaAlO_3$ were evaluated for $(LaAlO_3)_{1-x}(BaZrO_3)_x$ for x=0.02 and 0.05 in Experiments #39, #42, and #46. It was observed that for x=0.05, the major phase

was cubic, and for x = 0.02, nearly all the material showed cubic structure with $a_0 = 3.81 \text{Å}$. Traces of La(OH)₃ were also observed in the x-ray pattern. Similar results were also achieved when SrZrO₃ was added to LaAlO₃. The bluish-green crystals grown are not expected to exhibit blue-green fluorescence. Ce:BaZrO₃ did not exhibit any fluorescence.

The results of investigations of other perovskites have shown that in the compositions evaluated, enlarged cubic cells could not be formed by ordering. Small additions of less than 5% of BaZrO₃ or SrZrO₃ to LaAlO₃ produced cubic symmetry which should allow growth of twin-free crystals. The crystals grown did not exhibit blue-green fluorescence.

3.3 Evaluation of Low Melting Point Hosts

LaAlO $_3$ appears to be an appropriate host for Ce $^{3+}$ for bluegreen laser applications. However, because of phase transitions, twin-free crystals cannot be grown. Suitable additions to LaAlO $_3$ can be made to transform the structure to cubic phase which will eliminate the phase transitions. However, the crystal growth conditions required cannot be easily achieved with available equipment. An evaluation was made of lower melting point host materials which could be grown as single crystals.

For these purposes, efforts were made to grow Ce-doped crystals of Gd_2SiO_5 and La_2SiO_5 . These samples were sent to ONR for fluorescence measurements toward the end of the experimental program, but data was not obtained.

A sample of $\text{Pr:}K\text{MgY}_3\text{F}_{12}$ obtained from Airtron was also directionally solidified by HEM and sample sent to ONR.

Recent interest in Cr,Nd:Gd $_3$ Sc $_2$ Al $_3$ O $_{12}$ (GSAG) laser crystals prompted interest in evaluation of Ce:GSAG crystals. Yellow crystals approximately cm size were grown by HEM and evaluated at the Naval Research Laboratory. It was observed that emission varied with the pump wavelength. Three fluorescence peaks centered at 380, 485, and 795 nm were observed. The fluorescence spectra of Ce:GSAG with an excitation at 365 nm is shown in

Figure 6. While this material showed interesting results, the fluorescence data was received after the end of the experimental program. In order to further evaluate the laser performance of this crystal, it would be necessary to grow improved quality crystals using higher purity starting materials.

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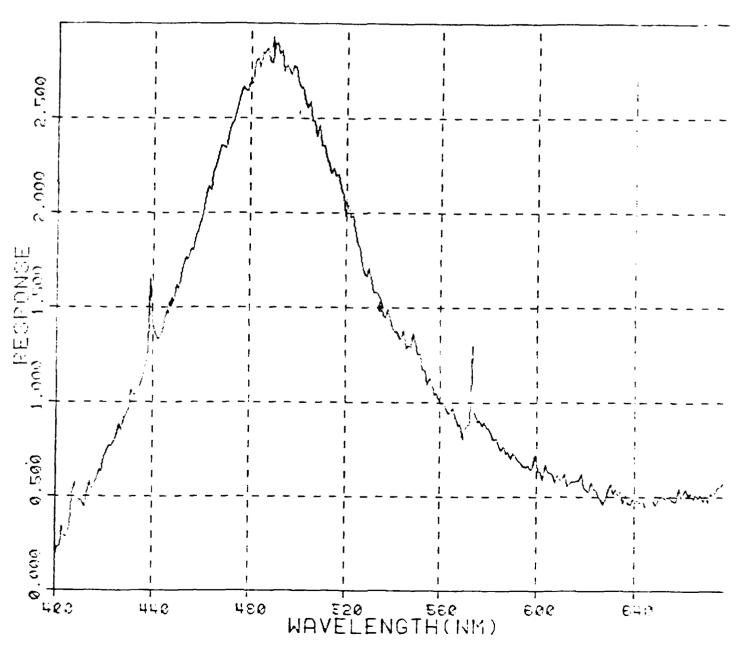
Figure 6.

S E P 2 4 A 2 . N M L Ce : Gd₃Sc₂A1₅O₁₂

Excitation = 365 nm

Fluorescence Spectra

Crystal Systems



4.0 Conclusions

Ce:LaAlO3 offers promise as a solid state laser crystal for communication under seawater. The phase transition at 435° C for LaAlO3 does not allow growth of high quality crystals. Initial emphasis of the program was on making suitable additions to the LaAlO3 in order to achieve a cubic perovskite structure which the phase transition. Α composition La(Alo 75Sco 25)03 was identified as cubic; however, high quality crystals could not be grown because of difficult crystal growth parameters which could not be obtained with available equipment. Two other compositions - (La_{0.98}Ba_{0.02})(Al_{0.98}Zr_{0.02})0₃ and $(La_{0.98}Sr_{0.02})(Al_{0.98}Zr_{0.02})0_3$ - were also produced with cubic structure. Since Ba containing compound may exhibit quenching of fluorescence, the Sr compound may be useful for solid state laser applications. These bluish-green crystals are not expected to show fluorescence in the blue-green spectral region.

In order to develop other crystals with lower melting point, an effort was also placed on $\text{Ce:}\text{Gd}_2\text{SiO}_5$, $\text{Ce:}\text{La}_2\text{SiO}_5$ and $\text{Pr:}\text{KMgY}_3\text{F}_{12}$. These samples were delivered to ONR for evaluation of fluorescence.

Ce: $\mathrm{Gd}_3\mathrm{Sc}_2\mathrm{Al}_3\mathrm{O}_{12}$ (Ce:GSAG) crystals were also grown by HEM. These crystals offer promise for solid state laser applications; however, it is necessary to grow improved quality crystals for evaluation of laser performance.

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